

10Gbps 850nm 300m XFP Optical Transceiver Module

S-XP1085L03-xD

Features

- Supports 9.953Gb/s to 11.1Gb/s bit rates
- Hot-pluggable XFP footprint, Built-in digital diagnos
- Maximum link length of 300m with MMF-OM3
- 850nm VCSEL laser and PIN photodiode
- XFP MSA package with duplex LC connector
- No reference clock required
- Single +3.3V power supply
- Power dissipation <1.5W
- Compatible with RoHS
- Temperature range: 0 to +70°C

Applications

- SONET OC-192&SDH STM-64 at 9.953Gbps
- 10GBASE-SR/SW 10G Ethernet
- 1200-MX-SN-I 10Gigabit Fiber Channel
- 10GE over G.709 at 11.09Gbps
- OC192 over FEC at 10.709Gbps
- Other optical links, up to 11.3Gbps

Description

XFP module is compliant with the 10G Small Form-Factor Pluggable (XFP) Multi-Source Agreement (MSA), supporting data-rate of 9.953~11.1Gbps, and transmission distance up to 300m with OM3 MMF.

The transceiver module comprises a transmitter with 850nm VCSEL laser and a receiver with a PIN photodiode. Transmitter and receiver are separate within a wide temperature range and offers optimum heat dissipation and excellent electromagnetic shielding thus enabling high port densities for 10 GbE systems.

Absolute Maximum Ratings

Parameter	Symbol	Min	Typ	Max	Unit
Power Supply Voltage	Vcc	-0.5		4.5	V
Storage Temperature Range	Ts	-40		+85	°C
Relative Humidity - Operating	RH _o	5		85	%

Any stress beyond the maximum ratings can result in permanent damage. The device specifications are guaranteed only under the recommended operating conditions.

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Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Case Operating Temperature Range	T _c	0		+70	°C
Power Supply Voltage	V _{cc}	3.135	3.30	3.465	V
Supply Current	I _{cc}			500	mA
Data Rate	BR	9.953		11.1	Gbps

Optical and Electrical Characteristics

Transmitter Electrical Characteristics						
Parameter	Symbol	Min	Typical	Max	Unit	Notes
Centre Wavelength	λ _c	840	850	860	nm	
Spectral Width (RMS)	Δλ			0.45	nm	
Side-Mode Suppression Ratio	SMSR	-	-	-	dB	
Average Output Power	P _{out}	-6.5		-0.5	dBm	1
Extinction Ratio	ER	3.0			dB	
Data Input Swing Differential	V _{IN}	180		950	mV	2
Input Differential Impedance	Z _{IN}	90	100	110	Ω	
TX Disable	Disable		2.0	V _{cc}	V	
	Enable		0	0.8	V	
Receiver Electrical Characteristics						
Parameter	Symbol	Min	Typ	Max	Unit	Notes
Centre Wavelength	λ _c	840		860	nm	
Receiver Sensitivity				-10.5	dBm	3
Receiver Overload		0.5			dBm	3
LOS De-Assert	LOS _D			-12	dBm	
LOS Assert	LOS _A	-26			dBm	
LOS Hysteresis		0.5		4	dB	
Data Output Swing Differential	V _{out}	400	600	800	mV	2
LOS	High	2.0		V _{cc}	V	
	Low			0.8	V	
Notes						
1. The optical power is launched into MMF.						
2. Internally AC-coupled.						
3. Measured with a PRBS 2 ³¹ -1 test pattern @9953Mbps, BER ≤1×10 ⁻¹² .						

Pin Definitions

Pin	Logic	Symbol	Name/Description	Ref
1		GND	Module Ground	1
2		VEE5	Optional -5.2 Power Supply – Not required	

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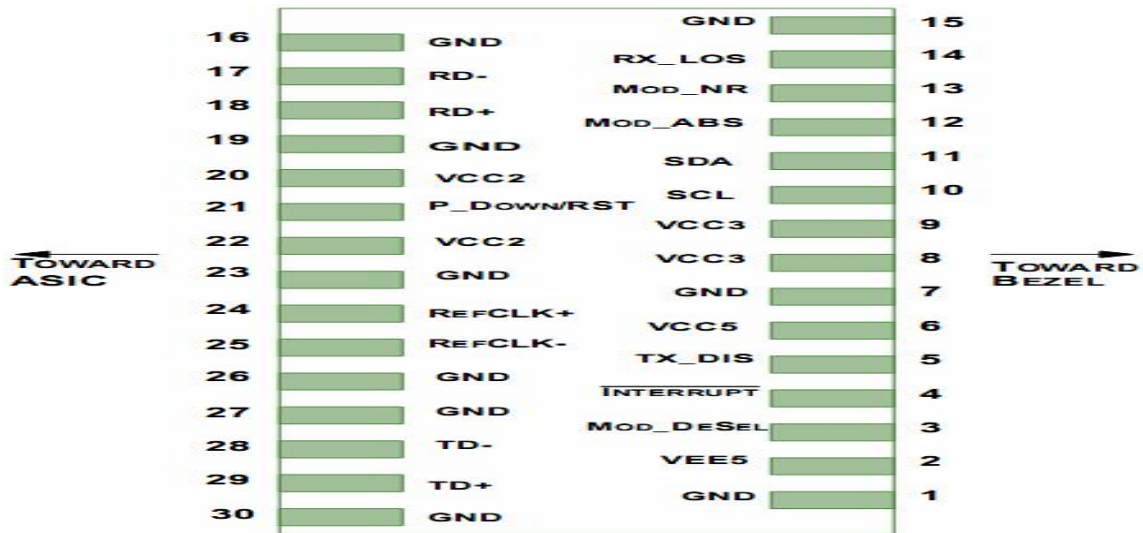
3	LVTTL-I	Mod-Desel	Module De-select; When held low allows the module to, respond to 2-wire serial interface commands	
4	LVTTL-O	Interrupt	Interrupt (bar); Indicates presence of an important condition which can be read over the serial 2-wire interface	2
5	LVTTL-I	TX_DIS	Transmitter Disable; Transmitter laser source turned off	
6		VCC5	+5 Power Supply – Not required	
7		GND	Module Ground	1
8		VCC3	+3.3V Power Supply	
9		VCC3	+3.3V Power Supply	
10	LVTTL-I	SCL	Serial 2-wire interface clock	2
11	LVTTL- I/O	SDA	Serial 2-wire interface data line	2
12	LVTTL-O	Mod_Abs	Module Absent; Indicates module is not present. Grounded in the module.	2
13	LVTTL-O	Mod_NR	Module Not Ready;	2
14	LVTTL-O	RX_LOS	Receiver Loss of Signal indicator	2
15		GND	Module Ground	1
16		GND	Module Ground	1
17	CML-O	RD-	Receiver inverted data output	
18	CML-O	RD+	Receiver non-inverted data output	
19		GND	Module Ground	1
20		VCC2	+1.8V Power Supply – Not required	
21	LVTTL-I	P_Down/RS T	Power Down; When high, places the module in the low power stand-by mode and on the falling edge of P_Down initiates a module reset	
			Reset; The falling edge initiates a complete reset of the module including the 2-wire serial interface, equivalent to a power cycle.	
22		VCC2	+1.8V Power Supply – Not required	
23		GND	Module Ground	1
24	PECL-I	RefCLK+	Reference Clock non-inverted input, AC coupled on the host board – Not required	3
25	PECL-I	RefCLK-	Reference Clock inverted input, AC coupled on the host board – Not required	3
26		GND	Module Ground	1
27		GND	Module Ground	1
28	CML-I	TD-	Transmitter inverted data input	
29	CML-I	TD+	Transmitter non-inverted data input	
30		GND	Module Ground	1

Notes

1. Module circuit ground is isolated from module chassis ground within the module.
2. Open collector, should be pulled up with 4.7k – 10k ohms on host board to a voltage between 3.15V and 3.6V.
3. A Reference Clock input is not required.

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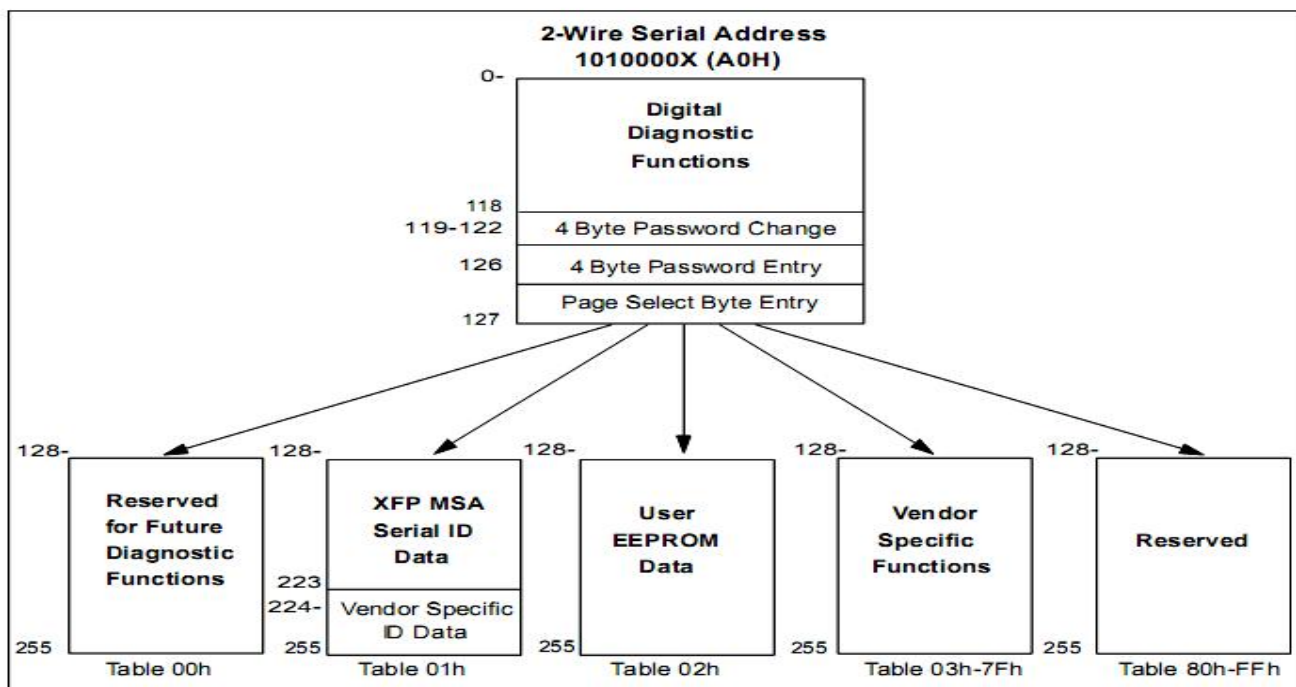


Management Interface

The transceivers provide serial ID memory contents and diagnostic information about the present operating conditions by the 2-wire serial interface (SCL, SDA).

The Module provides diagnostic information about the present operating conditions. The transceiver generates this diagnostic data by digitization of internal analog signals. Alarm/warning threshold data is written during device manufacture. Received power monitoring, transmitted power monitoring, bias current monitoring, supply voltage monitoring and temperature monitoring all are implemented.

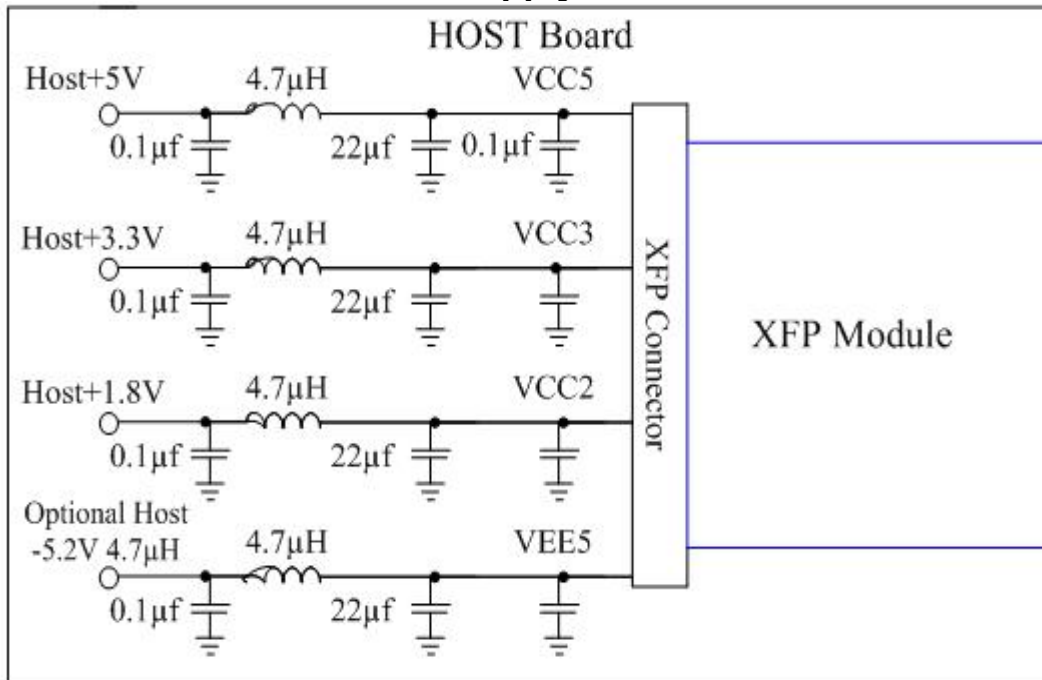
The digital diagnostic memory map specific data field defines as following.



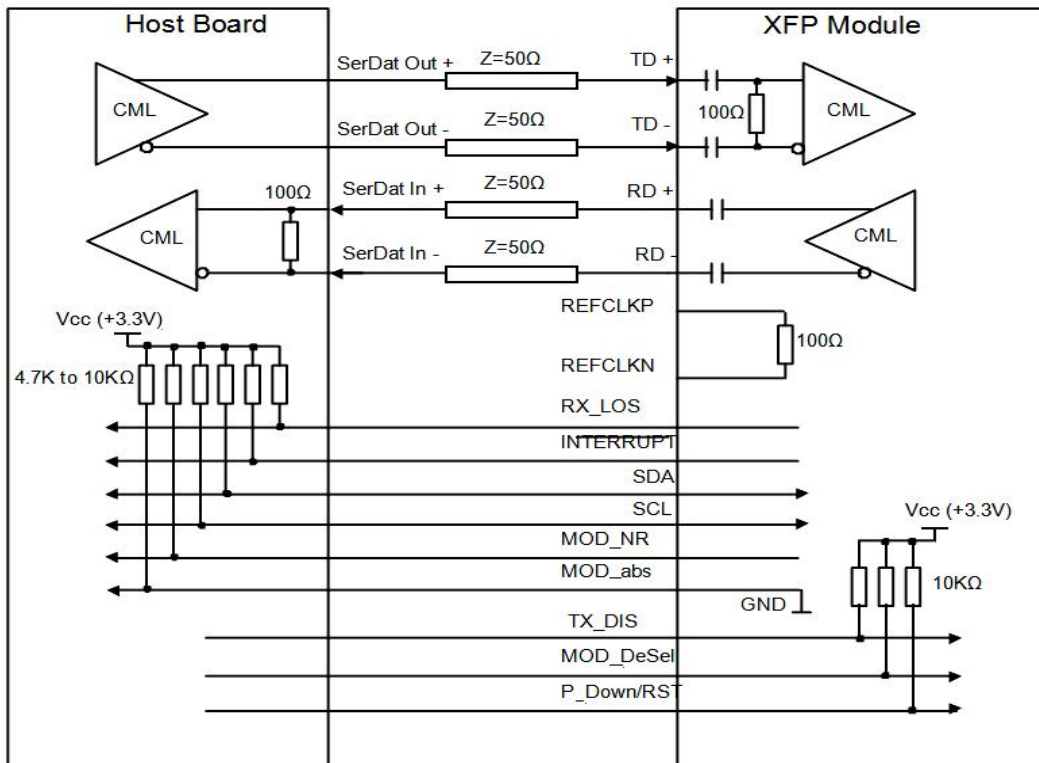
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Recommended Host Board Power Supply Circuit



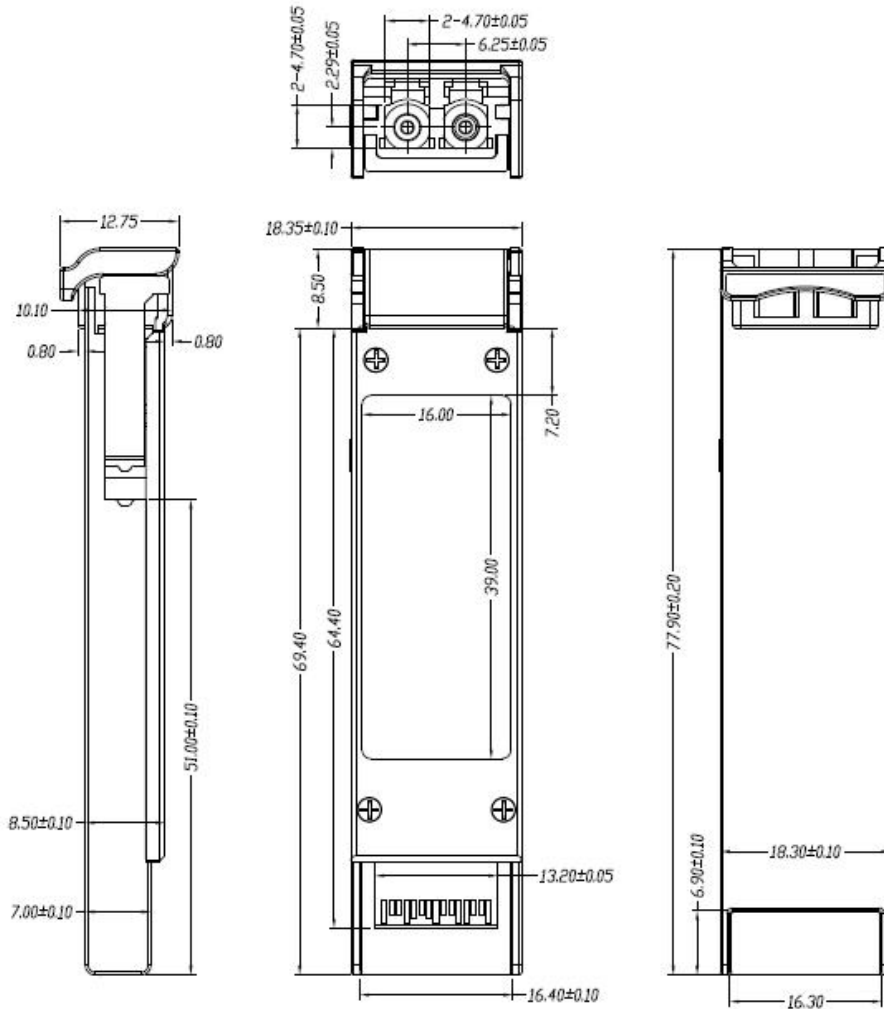
Recommended High-speed Interface Circuit



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Mechanical Dimensions



Ordering information

Part Number	Product Description
S-XP1085L03-CD	XFP, 10Gbps, 850nm, MM,300m, 0°C~+70°C, With DDM